## Features

- Transparent RF Receiver ICs for 315 MHz (ATA8201) and 433.92 MHz (ATA8202) With High Receiving Sensitivity
- Fully Integrated PLL With Low Phase Noise VCO, PLL, and Loop Filter
- High FSK/ASK Sensitivity:-105 dBm (ATA8201, FSK, 9.6 Kbits/s, Manchester, BER 10 ${ }^{\mathbf{- 3}}$ ) -114 dBm (ATA8201, ASK, 2.4 Kbits/s, Manchester, BER 10 ${ }^{-3}$ ) -104 dBm (ATA8202, FSK, 9.6 Kbits/s, Manchester, BER 10 ${ }^{-3}$ ) -113 dBm (ATA8202, ASK, 2.4 Kbits/s, Manchester, BER 10³)
- Supply Current: 6.5 mA in Active Mode (3V, $25^{\circ} \mathrm{C}$, ASK Mode)
- Data Rate: $1 \mathrm{Kbit} / \mathrm{s}$ to $10 \mathrm{Kbits} / \mathrm{s}$ Manchester ASK, $1 \mathrm{Kbit} / \mathrm{s}$ to $20 \mathrm{Kbits} / \mathrm{s}$ Manchester FSK With Four Programmable Bit Rate Ranges
- Switching Between Modulation Types ASK/FSK and Different Data Rates Possible in $\leq 1 \mathrm{~ms}$ Typically, Without Hardware Modification on Board to Allow Different Modulation Schemes
- Low Standby Current: $50 \mu \mathrm{~A}$ at $\mathbf{3 V}, \mathbf{2 5 ^ { \circ }} \mathrm{C}$
- ASK/FSK Receiver Uses a Low-IF Architecture With High Selectivity, Blocking, and Low Intermodulation (Typical 3-dB Blocking 68.0 dBC at $\pm 3 \mathrm{MHz} / 74.0 \mathrm{dBC}$ at $\pm 20.0 \mathrm{MHz}$, System I1dBCP = -31 dBm/System IIP3 = - $\mathbf{- 2 4} \mathbf{~ d B m ) ~}$
- Telegram Pause Up to 52 ms Supported in ASK Mode
- Wide Bandwidth AGC to Handle Large Out-of-band Blockers above the System I1dBCP
- 440-kHz IF Frequency With 30-dB Image Rejection and 420-kHz IF Bandwidth to Support PLL Transmitters With Standard Crystals or SAW-based Transmitters
- RSSI (Received Signal Strength Indicator) With Output Signal Dynamic Range of 65 dB
- Low In-band Sensitivity Change of Typically $\pm \mathbf{2 . 0} \mathbf{d B}$ Within $\pm 160-k H z$ Center Frequency Change in the Complete Temperature and Supply Voltage Range
- Sophisticated Threshold Control and Quasi-peak Detector Circuit in the Data Slicer
- Fast and Stable XTO Start-up Circuit (> -1.4 k $\Omega$ Worst-case Start Impedance)
- Clock Generation for Microcontroller
- ESD Protection at all Pins ( $\pm 4 \mathrm{kV}$ HBM, $\pm 200 \mathrm{~V}$ MM, $\pm 500 \mathrm{~V}$ FCDM)
- Dual Supply Voltage Range: 2.7 V to 3.3 V or 4.5 V to 5.5 V
- Temperature Range: $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$
- Small $5 \mathrm{~mm} \times 5 \mathrm{~mm}$ QFN24 Package


## Applications

- Industrial/Aftermarket Keyless Entry and Tire Pressure Monitoring Systems
- Alarm, Telemetering and Energy Metering Systems
- Remote Conrol Systems for Consumer and Industrial Markets
- Access Control Systems
- Home Automation
- Home Entertainment
- Toys


UHF ASK/FSK Receiver

## Benefits

- Supports Header and Blanking Periods of Protocols Common in RKE and TPM Systems (Up to 52 ms in ASK Mode)
- All RF Relevant Functions are Integrated. The Single-ended RF Input is Suited for Easy Adaptation to $\lambda / 4$ or Printed-loop Antennas
- Allows a Low-cost Application With Only 8 Passive Components
- Optimal Bandwidth Maximizes Sensitivity while Maintaining SAW Transmitter Compatibility
- Clock Output Provides an External Microcontroller Crystal-precision Time Reference
- Well Suited for Use With PLL Transmitter ATA5756/ATA5757


## ATA8201/ATA8202

## 1. General Description

The ATA8201/ATA8202 is a UHF ASK/FSK transparent receiver IC with low power consumption supplied in a small QFN24 package (body $5 \mathrm{~mm} \times 5 \mathrm{~mm}$, pitch 0.65 mm ). ATA8202 is used in the 433 MHz to 435 MHz band of operation, and ATA8201 in 313 MHz to 317 MHz .

For improved image rejection and selectivity, the IF frequency is fixed to 440 kHz . The IF block uses an 8th-order band pass yielding a receive bandwidth of 420 kHz . This enables the use of the receiver in both SAW- and PLL-based transmitter systems utilizing various types of data-bit encoding such as pulse width modulation, Manchester modulation, variable pulse modulation, pulse position modulation, and NRZ. Prevailing encryption protocols such as Keeloq ${ }^{\circledR}$ are easily supported due to the receiver's ability to hold the current data slicer threshold for up to 52 ms when incoming RF telegrams contain a blanking interval. This feature eliminates erroneous noise from appearing on the demodulated data output pin, and simplifies software decoding algorithms. The decoding of the data stream must be carried out by a connected microcontroller device. Because of the highly integrated design, the only required RF components are for the purpose of receiver antenna matching.

ATA8201 and ATA8202 support Manchester bit rates of $1 \mathrm{Kbit} / \mathrm{s}$ to $10 \mathrm{Kbits} / \mathrm{s}$ in ASK and $1 \mathrm{Kbit} / \mathrm{s}$ to $20 \mathrm{Kbits} / \mathrm{s}$ in FSK mode. The four discrete bit rate passbands are selectable and cover 1.0 Kbit/s to $2.5 \mathrm{Kbits} / \mathrm{s}$, 2.0 Kbits/s to 5.0 Kbits/s, 4.0 Kbits/s to $10.0 \mathrm{Kbits} / \mathrm{s}$, and $8.0 \mathrm{Kbits} / \mathrm{s}$ to $10.0 \mathrm{Kbits} / \mathrm{s}$ or $20.0 \mathrm{Kbits} / \mathrm{s}$ (for ASK or FSK, respectively). The receiver contains an RSSI output to provide an indication of received signal strength and a SENSE input to allow the customer to select a threshold below which the DATA signal is gated off. ASK/FSK and bit rate ranges are selected by the connected microcontroller device via pins ASK_NFSK, BRO, and BR1.

Figure 1-1. System Block Diagram


Figure 1-2. Pinning QFN24


Table 1-1. Pin Description

| Pin | Symbol | Function |
| :---: | :---: | :--- |
| 1 | TEST2 | Test pin, during operation at GND |
| 2 | TEST1 | Test pin, during operation at GND |
| 3 | CLK_OUT | Output to clock a connected microcontroller |
| 4 | CLK_OUT_CTRL1 | Input to control CLK_OUT (MSB) |
| 5 | CLK_OUT_CTRLO | Input to control CLK_OUT (LSB) |
| 6 | ENABLE | Input to enable the XTO |
| 7 | XTAL2 | Reference crystal |
| 8 | XTAL1 | Reference crystal |
| 9 | DVCC | Digital voltage supply blocking |
| 10 | VS5V | Power supply input for voltage range 4.5V to 5.5V |
| 11 | VS3V_AVCC | Power supply input for voltage range 2.7 V to 3.3 V |
| 12 | GND | Ground |
| 13 | LNA_GND | RF ground |
| 14 | LNA_IN | RF input |
| 15 | SENSE | Sensitivity control resistor |
| 16 | SENSE_CTRL | Sensitivity selection <br> Low: <br> 17$\quad$ RSormal sensitivity, High: Reduced sensitivity |
| 18 | TEST3 | Output of the RSSI amplifier |
| 19 | RX | Test pin, during operation at GND |
| 20 | Input to activate the receiver |  |
| 21 | BRO | Bit rate selection, LSB |
| 22 | ASK_NFSK | Bit rate selection, MSB |
| 23 | CSK/ASK selection |  |
| 24 | Cow: FSK, High: ASK |  |
|  | CATA_OUT | Capacitor to adjust the lower cut-off frequency data filter |
|  | Data output |  |

Figure 1-3. Block Diagram


## 2. RF Receiver

As seen in Figure 1-3 on page 5, the RF receiver consists of a low-noise amplifier (LNA), a local oscillator, and the signal processing part with mixer, IF filter, IF amplifier with analog RSSI, FSK/ASK demodulator, data filter, and data slicer.

In receive mode, the LNA pre-amplifies the received signal which is converted down to a $440-\mathrm{kHz}$ intermediate frequency (IF), then filtered and amplified before it is fed into an FSK/ASK demodulator, data filter, and data slicer. The received signal strength indicator (RSSI) signal is available at the pin RSSI.

### 2.1 Low-IF Receiver

The receive path consists of a fully integrated low-IF receiver. It fulfills the sensitivity, blocking, selectivity, supply voltage, and supply current specification needed to design, e.g., an industrial/ aftermarket integrated receiver for RKE and TPM systems. A benefit of the integrated receive filter is that no external components needed.

At 315 MHz , the ATA8201 receiver ( 433.92 MHz for the ATA8202 receiver) has a typical system noise figure of $6.0 \mathrm{~dB}(7.0 \mathrm{~dB})$, a system I1dBCP of $-31 \mathrm{dBm}(-30 \mathrm{dBm})$, and a system IIP3 of $-24 \mathrm{dBm}(-23 \mathrm{dBm})$. The signal path is linear for out-of-band disturbers up to the I1dBCP and hence there is no AGC or switching of the LNA needed, and a better blocking performance is achieved. This receiver uses an IF (intermediate frequency) of 440 kHz , the typical image rejection is 30 dB and the typical $3-\mathrm{dB}$ IF filter bandwidth is $420 \mathrm{kHz}\left(\mathrm{f}_{\mathrm{IF}}=440 \mathrm{kHz} \pm 210 \mathrm{kHz}\right.$, $f_{\text {lo_IF }}=230 \mathrm{kHz}$ and $\mathrm{f}_{\text {hi_IF }}=650 \mathrm{kHz}$ ). The demodulator needs a signal-to-noise ratio of 8.5 dB for 10 Kbits/s Manchester with $\pm 38 \mathrm{kHz}$ frequency deviation in FSK mode, thus, the resulting sensitivity at $315 \mathrm{MHz}(433.92 \mathrm{MHz})$ is typically $-105 \mathrm{dBm}(-104 \mathrm{dBm})$.

Due to the low phase noise and spurs of the synthesizer together with the 8th-order integrated IF filter, the receiver has a better selectivity and blocking performance than more complex double superhet receivers, without using external components and without numerous spurious receiving frequencies.
A low-IF architecture is also less sensitive to second-order intermodulation (IIP2) than direct conversion receivers where every pulse or amplitude modulated signal (especially the signals from TDMA systems like GSM) demodulates to the receiving signal band at second-order non-linearities.

## ATA8201/ATA8202

### 2.2 Input Matching at LNA_IN

The measured input impedances as well as the values of a parallel equivalent circuit of these impedances can be seen in Table 2-1. The highest sensitivity is achieved with power matching of these impedances to the source impedance.

Table 2-1. $\quad$ Measured Input Impedances of the LNA_IN Pin

| $\mathbf{f}_{\mathbf{R F}}[\mathbf{M H z}]$ | $\mathbf{Z}_{\text {ln }}\left(\mathbf{R F}_{-} \mathbf{I N}\right)[\Omega]$ | $\mathbf{R}_{\text {ln } \mathbf{p}} / / \mathbf{C}_{\text {ln } n}[\mathbf{p F}]$ |
| :---: | :---: | :---: |
| 315 | $(72.4-\mathrm{j} 298)$ | $1300 \Omega / 1.60$ |
| 433.92 | $(55-\mathrm{j} 216)$ | $900 \Omega / 1.60$ |

The matching of the LNA input to $50 \Omega$ is done using the circuit shown in Figure 2-1 and the values of the matching elements given in Table 2-2. The reflection coefficients were always $\leq-10 \mathrm{~dB}$. Note that value changes of C1 and L1 may be necessary to compensate individual board layout parasitics. The measured typical FSK and ASK Manchester-code sensitivities with a bit error rate (BER) of $10^{-3}$ are shown in Table 2-3 and Table 2-4 on page 8. These measurements were done with wire-wound inductors having quality factors reported in Table 2-2, resulting in estimated matching losses of 0.8 dB at 315 MHz and 433.92 MHz . These losses can be estimated when calculating the parallel equivalent resistance of the inductor with $R_{\text {loss }}=2 \times \pi \times f \times L \times Q_{\text {L }}$ and the matching loss with $10 \log \left(1+R_{\text {ln_p }} / R_{\text {loss }}\right)$.

Figure 2-1. Input Matching to $50 \Omega$


Table 2-2. Input Matching to $50 \Omega$

| $\mathbf{f}_{\mathbf{R F}}[\mathbf{M H z}]$ | $\mathbf{C}_{\mathbf{1}}[\mathbf{p F}]$ | $\mathbf{L}_{\mathbf{1}}[\mathbf{n H}]$ | $\mathbf{Q}_{\mathbf{L 1}}$ |
| :---: | :---: | :---: | :---: |
| 315 | 2.2 | 68 | 20 |
| 433.92 | 2.2 | 36 | 15 |

Table 2-3. $\quad$ Measured Typical Sensitivity FSK, $\pm 38 \mathrm{kHz}$, Manchester, BER $=10^{-3}$

| RF Frequency | BR_Range_0 <br> $\mathbf{1 . 0 ~ K b i t / s ~}$ | BR_Range_0 <br> $\mathbf{2 . 5} \mathbf{~ K b i t s / s ~}$ | BR_Range_1 <br> $\mathbf{5} \mathbf{K b i t s} / \mathbf{s}$ | BR_Range_2 <br> $\mathbf{1 0 ~ K b i t s / s ~}$ | BR_Range_3 <br> $\mathbf{1 0} \mathbf{K b i t s} / \mathbf{s}$ | BR_Range_3 <br> 20 Kbits/s |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 315 MHz | -108 dBm | -108 dBm | -107 dBm | -105 dBm | -104 dBm | -104 dBm |
| 433.92 MHz | -107 dBm | -107 dBm | -106 dBm | -104 dBm | -103 dBm | -103 dBm |

Table 2-4. Measured Typical Sensitivity $100 \%$ ASK, Manchester, BER $=10^{-3}$

| RF Frequency | BR_Range_0 <br> $\mathbf{1 . 0 ~ K b i t / s ~}$ | BR_Range_0 <br> $\mathbf{2 . 5} \mathbf{K b i t s} / \mathbf{s}$ | BR_Range_1 <br> 5 Kbits/s | BR_Range_2 <br> $\mathbf{1 0}$ Kbits/s | BR_Range_3 <br> 10 Kbits/s |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 315 MHz | -114 dBm | -114 dBm | -113 dBm | -111 dBm | -109 dBm |
| 433.92 MHz | -113 dBm | -113 dBm | -112 dBm | -110 dBm | -108 dBm |

Conditions for the sensitivity measurement:
The given sensitivity values are valid for Manchester-modulated signals. For the sensitivity measurement the distance from edge to edge must be evaluated. As can be seen in Figure 6-1 on page 25, in a Manchester-modulated data stream, the time segments $T_{E E}$ and $2 \times T_{E E}$ occur.

To reach the specified sensitivity for the evaluation of $T_{E E}$ and $2 \times T_{E E}$ in the data stream, the following limits should be used ( $T_{E E} \min , T_{E E} \max , 2 \times T_{E E} \min , 2 \times T_{E E} \max$ ).

Table 2-5. Limits for Sensitivity Measurements

| Bit Rate | $\mathbf{T}_{\text {EE }} \mathbf{M i n}$ | $\mathbf{T}_{\text {EE }} \mathbf{T y p}$ | $\mathbf{T}_{\text {EE }} \mathbf{M a x}$ | $\mathbf{2 \times \mathbf { T } _ { \mathrm { EE } }} \mathbf{M i n}$ | $\mathbf{2 \times \mathbf { T } _ { E E }} \mathbf{T y p}$ | $\mathbf{2 \times \mathbf { T } _ { \mathrm { EE } }} \mathbf{M a x}$ |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $1.0 \mathrm{Kbit} / \mathrm{s}$ | $260 \mu \mathrm{~s}$ | $500 \mu \mathrm{~s}$ | $790 \mu \mathrm{~s}$ | $800 \mu \mathrm{~s}$ | $1000 \mu \mathrm{~s}$ | $1340 \mu \mathrm{~s}$ |
| $2.4 \mathrm{Kbits} / \mathrm{s}$ | $110 \mu \mathrm{~s}$ | $208 \mu \mathrm{~s}$ | $310 \mu \mathrm{~s}$ | $320 \mu \mathrm{~s}$ | $416 \mu \mathrm{~s}$ | $525 \mu \mathrm{~s}$ |
| $5.0 \mathrm{Kbits} / \mathrm{s}$ | $55 \mu \mathrm{~s}$ | $100 \mu \mathrm{~s}$ | $155 \mu \mathrm{~s}$ | $160 \mu \mathrm{~s}$ | $200 \mu \mathrm{~s}$ | $260 \mu \mathrm{~s}$ |
| $9.6 \mathrm{Kbits} / \mathrm{s}$ | $27 \mu \mathrm{~s}$ | $52 \mu \mathrm{~s}$ | $78 \mu \mathrm{~s}$ | $81 \mu \mathrm{~s}$ | $104 \mu \mathrm{~s}$ | $131 \mu \mathrm{~s}$ |

### 2.3 Sensitivity Versus Supply Voltage, Temperature and Frequency Offset

To calculate the behavior of a transmission system, it is important to know the reduction of the sensitivity due to several influences. The most important are frequency offset due to crystal oscillator (XTO) and crystal frequency (XTAL) errors, temperature and supply voltage dependency of the noise figure, and IF-filter bandwidth of the receiver. Figure 2-2 and Figure 2-3 on page 9 show the typical sensitivity at 315 MHz, ASK, 2.4 Kbits/s and $9.6 \mathrm{Kbits} / \mathrm{s}$, Manchester, Figure $2-4$ and Figure $2-5$ on page 10 show a typical sensitivity at $315 \mathrm{MHz}, \mathrm{FSK}, 2.4 \mathrm{Kbits} / \mathrm{s}$ and $9.6 \mathrm{Kbits} / \mathrm{s}, \pm 38 \mathrm{kHz}$, Manchester versus the frequency offset between transmitter and receiver at $\mathrm{T}_{\mathrm{amb}}=+25^{\circ} \mathrm{C}$ and supply voltage $\mathrm{VS}=\mathrm{VS} 3 \mathrm{~V} \_A V C C=\mathrm{VS5V}=3.0 \mathrm{~V}$.

Figure 2-2. Measured Sensitivity ( $315 \mathrm{MHz}, \mathrm{ASK}, 2.4 \mathrm{Kbits} / \mathrm{s}$, Manchester) Versus Frequency Offset

Input Sensitivity (dBm) at BER < 1e-3, ATA8201, ASK, 2.4 kB/s (Manchester), $B R=0$


Figure 2-3. $\quad$ Measured Sensitivity ( $315 \mathrm{MHz}, \mathrm{ASK}, 9.6 \mathrm{Kbits} / \mathrm{s}$, Manchester) Versus Frequency Offset
Input Sensitivity (dBm) at BER < 1e-3, ATA8201, ASK, 9.6 Kbits/s (Manchester), $B R=2$


Figure 2-4. Measured Sensitivity ( $315 \mathrm{MHz}, \mathrm{FSK}, 2.4 \mathrm{Kbits} / \mathrm{s}, \pm 38 \mathrm{kHz}$, Manchester) Versus Frequency Offset

Input Sensitivity (dBm) at BER < 1e-3, ATA8201, FSK, 2.4 Kbits/s
(Manchester), BRO


Figure 2-5. Measured Sensitivity ( $315 \mathrm{MHz}, \mathrm{FSK}, 9.6 \mathrm{Kbits} / \mathrm{s}, \pm 38 \mathrm{kHz}$, Manchester) Versus Frequency Offset

Input Sensitivity (dBm) at BER < 1e-3, ATA8201, FSK, 9.6 Kbits/s (Manchester), $B R=2$


## ATA8201/ATA8202

As can be seen in Figure 2-5 on page 10, the supply voltage has almost no influence. The temperature has an influence of about $\pm 1.0 \mathrm{~dB}$, and a frequency offset of $\pm 160 \mathrm{kHz}$ also influences by about $\pm 1 \mathrm{~dB}$. All these influences, combined with the sensitivity of a typical IC ( -105 dB ), are then within a range of -103.0 dBm and -107.0 dBm over temperature, supply voltage, and frequency offset. The integrated IF filter has an additional production tolerance of $\pm 10 \mathrm{kHz}$, hence, a frequency offset between the receiver and the transmitter of $\pm 160 \mathrm{kHz}$ can be accepted for XTAL and XTO tolerances.

Note: For the demodulator used in the ATA8201/ATA8202, the tolerable frequency offset does not change with the data frequency. Hence, the value of $\pm 160 \mathrm{kHz}$ is valid for $1 \mathrm{Kbit} / \mathrm{s}$ to $10 \mathrm{Kbits} / \mathrm{s}$.
This small sensitivity change over supply voltage, frequency offset, and temperature is very unusual in such a receiver. It is achieved by an internal, very fast, and automatic frequency correction in the FSK demodulator after the IF filter, which leads to a higher system margin. This frequency correction tracks the input frequency very quickly. If, however, the input frequency makes a larger step (for example, if the system changes between different communication partners), the receiver has to be restarted. This can be done by switching back to Standby mode and then again to Active mode (pin RX $1 \rightarrow 0 \rightarrow 1$ ) or by generating a positive pulse on pin ASK_NFSK $(0 \rightarrow 1 \rightarrow 0)$.

### 2.4 RX Supply Current Versus Temperature and Supply Voltage

Table 2-7 shows the typical supply current of the receiver in Active mode versus supply voltage and temperature with VS $=$ VS3V_AVCC $=$ VS5V.

Table 2-6. Measured Current in Active Mode ASK

| VS $=$ VS3V_AVCC $=$ VS5V | 3.0 V |
| :---: | :---: |
| $\mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ | 6.5 mA |

Table 2-7. Measured Current in Active Mode FSK

| VS $=$ VS3V_AVCC $=$ VS5V | 3.0V |
| :---: | :---: |
| $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ | 6.7 mA |

### 2.5 Blocking, Selectivity

As can be seen in Figure 2-6 on page 12, and Figure $2-7$ and Figure $2-8$ on page 13, the receiver can receive signals 3 dB higher than the sensitivity level in the presence of large blockers of -34.5 dBm or -28 dBm with small frequency offsets of $\pm 3 \mathrm{MHz}$ or $\pm 20 \mathrm{MHz}$.

Figure 2-6, and Figure 2-7 on page 12 show the narrow-band blocking, and Figure $2-8$ on page 13 shows the wide-band blocking characteristic. The measurements were done with a useful signal of 315 MHz, FSK, $10 \mathrm{Kbits} / \mathrm{s}, \pm 38 \mathrm{kHz}$, Manchester, BR_Range2 with a level of $-105 \mathrm{dBm}+3 \mathrm{~dB}=-102 \mathrm{dBm}$, which is 3 dB above the sensitivity level. The figures show how much larger than -102 dBm a continuous wave signal can be, until the BER is higher than $10^{-3}$. The measurements were done at the $50 \Omega$ input shown in Figure $2-1$ on page 7. At 3 MHz , for example, the blocker can be 67.5 dBC higher than -102 dBm , or $-102 \mathrm{dBm}+67.5 \mathrm{dBC}=-34.5 \mathrm{dBm}$.

Figure 2-6. Close-in 3-dB Blocking Characteristic and Image Response at 315 MHz


Figure 2-7. Narrow-band 3-dB Blocking Characteristic at 315 MHz


Figure 2-8. Wide-band 3-dB Blocking Characteristic at 315 MHz


Table 2-8 shows the blocking performance measured relative to -102 dBm for some frequencies. Note that sometimes the blocking is measured relative to the sensitivity level 104 dBm (denoted dBS), instead of the carrier -102 dBm (denoted dBC)

Table 2-8. Blocking 3 dB Above Sensitivity Level With BER $<10^{-3}$

| Frequency Offset | Blocking Level | Blocking |
| :---: | :---: | :---: |
| +1.5 MHz | -44.5 dBm | $57.5 \mathrm{dBC}, 60.5 \mathrm{dBS}$ |
| -1.5 MHz | -44.5 dBm | $57.5 \mathrm{dBC}, 60.5 \mathrm{dBS}$ |
| +2 MHz | -39.0 dBm | $63 \mathrm{dBC}, 66 \mathrm{dBS}$ |
| -2 MHz | -36.0 dBm | $66 \mathrm{dBC}, 69 \mathrm{dBS}$ |
| +3 MHz | -34.5 dBm | $67.5 \mathrm{dBC}, 70.5 \mathrm{dBS}$ |
| -3 MHz | -34.5 dBm | $67.5 \mathrm{dBC}, 70.5 \mathrm{dBS}$ |
| +20 MHz | -28.0 dBm | $74 \mathrm{dBC}, 77 \mathrm{dBS}$ |
| -20 MHz | -28.0 dBm | $74 \mathrm{dBC}, 77 \mathrm{dBS}$ |

The ATA8201/ATA8202 can also receive FSK and ASK modulated signals if they are much higher than the 11 dBCP . It can typically receive useful signals at -10 dBm . This is often referred to as the nonlinear dynamic range (that is, the maximum to minimum receiving signal), and is 95 dB for $10 \mathrm{Kbits} / \mathrm{s}$ Manchester (FSK). This value is useful if the transmitter and receiver are very close to each other.

### 2.6 In-band Disturbers, Data Filter, Quasi-peak Detector, Data Slicer

If a disturbing signal falls into the received band, or if a blocker is not a continuous wave, the performance of a receiver strongly depends on the circuits after the IF filter. Hence, the demodulator, data filter, and data slicer are important.

The data filter of the ATA8201/ATA8202 functions also as a quasi-peak detector. This results in a good suppression of above mentioned disturbers and exhibits a good carrier-to-noise performance. The required useful-signal-to-disturbing-signal ratio, at a BER of $10^{-3,}$, is less than 14 dB in ASK mode and less than 3 dB (BR_Range_0 to BR_Range_2) and 6 dB (BR_Range_3) in FSK mode. Due to the many different possible waveforms, these numbers are measured for the signal, as well as for disturbers, with peak amplitude values. Note that these values are worst-case values and are valid for any type of modulation and modulating frequency of the disturbing signal, as well as for the receiving signal. For many combinations, lower carrier-to-disturbing-signal ratios are needed.

### 2.7 RSSI Output

The output voltage of the pin RSSI is an analog voltage, proportional to the input power level. Using the RSSI output signal, the signal strength of different transmitters can be distinguished. The usable dynamic range of the RSSI amplifier is 65 dB , the input power range $\mathrm{P}\left(\mathrm{RF}_{\text {IN }}\right)$ is -110 dBm to -45 dBm , and the gain is $15 \mathrm{mV} / \mathrm{dB}$. Figure 2-9 shows the RSSI characteristic of a typical device at 315 MHz with VS3V_AVCC $=\mathrm{VS5V}=3 \mathrm{~V}$ and $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ with a matched input as shown in Table 2-2 and Figure 2-1 on page 7. At $433.92 \mathrm{MHz}, 1 \mathrm{~dB}$ more signal level is needed for the same RSSI results.

Figure 2-9. Typical RSSI Characteristic at 315 MHz Versus Temperature and Supply Voltage


As can be seen in Figure 2-9 on page 14, for single devices there is a variance over temperature and supply voltage range of $\pm 3 \mathrm{~dB}$. The total variance over production, temperature, and supply voltage range is $\pm 9 \mathrm{~dB}$.

## ATA8201/ATA8202

### 2.8 Frequency Synthesizer

The LO generates the carrier frequency for the mixer via a PLL synthesizer. The XTO (crystal oscillator) generates the reference frequency $\mathrm{f}_{\mathrm{XTO}}$. The VCO (voltage-controlled oscillator) generates the drive voltage frequency $f_{\text {LO }}$ for the mixer. $f_{L O}$ is divided by the factor 24 (ATA8201) or 32 (ATA8202). The divided frequency is compared to $f_{\text {XTO }}$ by the phase frequency detector. The current output of the phase frequency detector is connected to the fully integrated loop filter, and thereby generates the control voltage for the VCO. By means of that configuration, the VCO is controlled in a way, such that $f_{L O} / 24\left(f_{L O} / 32\right)$ is equal to $f_{\text {XTO }}$. If $f_{L O}$ is determined, $f_{\text {XTO }}$ can be calculated using the following formula: $\mathrm{f}_{\mathrm{XTO}}=\mathrm{f}_{\mathrm{LO}} / 24$ ( $\mathrm{f}_{\mathrm{XTO}}=\mathrm{f}_{\mathrm{LO}} / 32$ ). The synthesizer has a phase noise of $-130 \mathrm{dBC} / \mathrm{Hz}$ at 3 MHz and spurs of -75 dBC .
Care must be taken with the harmonics of the CLK output signal, as well as with the harmonics produced by a microprocessor clocked using the signal, as these harmonics can disturb the reception of signals.

## 3. XTO

The XTO is an amplitude-regulated Pierce oscillator type with external load capacitances ( $2 \times 16 \mathrm{pF}$ ). Due to additional internal and board parasitics ( $\mathrm{C}_{\mathrm{p}}$ ) of approximately 2 pF on each side, the load capacitance amounts to $2 \times 18 \mathrm{pF}$ ( 9 pF total).

The XTO oscillation frequency $\mathrm{f}_{\text {хто }}$ is the reference frequency for the integer- N synthesizer. When designing the system in terms of receiving and transmitting frequency offset, the accuracy of the crystal and XTO have to be considered.
The XTO's additional pulling (including the $R_{M}$ tolerance) is only $\pm 5 \mathrm{ppm}$. The XTAL versus temperature, aging, and tolerances is then the main source of frequency error in the local oscillator.
The XTO frequency depends on XTAL properties and the load capacitances $\mathrm{C}_{\mathrm{L} 1,2}$ at pin XTAL1 and XTAL2. The pulling ( $p$ ) of $f_{\text {XTO }}$ from the nominal $f_{\text {XTAL }}$ is calculated using the following formula:

$$
p=\frac{C_{m}}{2} \times \frac{C_{L N}-C_{L}}{\left(C_{O}+C_{L N}\right) \times\left(C_{O}+C_{L}\right)} \times 10^{-6} \mathrm{ppm}
$$

$\mathrm{C}_{\mathrm{m}}$, the crystal's motional capacitance; $\mathrm{C}_{0}$, the shunt capacitance; and $\mathrm{C}_{\mathrm{LN}}$, the nominal load capacitance of the XTAL, are found in the datasheet. $\mathrm{C}_{\mathrm{L}}$ is the total actual load capacitance of the crystal in the circuit, and consists of $\mathrm{C}_{\mathrm{L} 1}$ and $\mathrm{C}_{\mathrm{L} 2}$ connected in series.

Figure 3-1. Crystal Equivalent Circuit


With $\mathrm{C}_{\mathrm{m}} \leq 10 \mathrm{fF}, \mathrm{C}_{0} \geq 1.0 \mathrm{pF}, \mathrm{C}_{\mathrm{LN}}=9 \mathrm{pF}$ and $\mathrm{C}_{\mathrm{L} 1,2}=16 \mathrm{pF} \pm 1 \%$, the pulling amounts to $\mathrm{P} \leq \pm 1 \mathrm{ppm}$.
The $\mathrm{C}_{0}$ of the XTAL has to be lower than $\mathrm{C}_{\mathrm{Lmin}} / 2=7.9 \mathrm{pF}$ for a Pierce oscillator type in order to not enter the steep region of pulling versus load capacitance where there is risk of an unstable oscillation.

To ensure proper start-up behavior, the small signal gain and the negative resistance provided by this XTO at start is very large. For example, oscillation starts up even in the worst case with a crystal series resistance of $1.5 \mathrm{k} \Omega$ at $\mathrm{C}_{0} \leq 2.2 \mathrm{pF}$ with this XTO. The negative resistance is approximately given by
$\operatorname{Re}\{Z x t o c o r e\}=\operatorname{Re}\left\{\frac{Z_{1} \times Z_{3}+Z_{2} \times Z_{3}+Z_{1} \times Z_{3} \times g m}{Z_{1}+Z_{2}+Z_{3}+Z_{1} \times Z_{2} \times g m}\right\}$
with $Z_{1}$ and $Z_{2}$ as complex impedances at pins XTAL1 and XTAL2, hence
$Z_{1}=-j /\left(2 \times p \times f_{\text {XTO }} \times C_{L 1}\right)+5 \Omega$ and $Z_{2}=-j /\left(2 \times p \times f_{\text {XTO }} \times C_{L 2}\right)+5 \Omega$
$Z_{3}$ consists of crystal $C_{0}$ in parallel with an internal 110-k resistor, hence
$Z_{3}=-j /\left(2 \times p \times f_{\text {XTO }} \times C_{0}\right) / 110 \mathrm{k} \Omega$, gm is the internal transconductance between XTAL1 and XTAL2, with typically 20 mS at $25^{\circ} \mathrm{C}$.
With $\mathrm{f}_{\text {хто }}=13.5 \mathrm{MHz}$, gm $=20 \mathrm{mS}, \mathrm{C}_{\mathrm{L}}=9 \mathrm{pF}$, and $\mathrm{C}_{0}=2.2 \mathrm{pF}$, this results in a negative resistance of about $2 \mathrm{k} \Omega$ The worst case for technology, supply voltage, and temperature variations is then always higher than $1.4 \mathrm{k} \Omega$ for $\mathrm{C}_{0} \leq 2.2 \mathrm{pF}$.

Due to the large gain at start, the XTO is able to meet a very low start-up time. The oscillation start-up time can be estimated with the time constant $\tau$.
$\tau=\frac{2}{4 \times \pi^{2} \times \mathrm{f}_{\text {XTAL }}{ }^{2} \times \mathrm{C}_{\mathrm{m}} \times\left(\operatorname{Re}\left(\mathrm{Z}_{\text {xtocore }}\right)+\mathrm{R}_{\mathrm{m}}\right)}$
After $10 \tau$ to $20 \tau$, an amplitude detector detects the oscillation amplitude and sets XTO_OK to High if the amplitude is large enough; this activates the CLK_OUT output if it is enabled via the pins CLK_OUT_CTRLO and CLK_OUT_CTRL1. Note that the necessary conditions of the DVCC voltage also have to be fulfilled.

It is recommended to use a crystal with $C_{m}=3.0 \mathrm{fF}$ to $10 \mathrm{fF}, \mathrm{C}_{\mathrm{LN}}=9 \mathrm{pF}, \mathrm{R}_{\mathrm{m}}<120 \Omega$ and $\mathrm{C}_{0}=1.0 \mathrm{pF}$ to 2.2 pF .
Lower values of $\mathrm{C}_{\mathrm{m}}$ can be used, slightly increasing the start-up time. Lower values of $\mathrm{C}_{0}$ or higher values of $\mathrm{C}_{\mathrm{m}}$ (up to 15 fF ) can also be used, with only little influence on pulling.

Figure 3-2. XTO Block Diagram


The relationship between $f_{\text {XTO }}$ and the $f_{R F}$ is shown in Table 3-1.

Table 3-1. $\quad$ Calculation of $f_{R F}$

| Frequency [MHz] | $\mathbf{f}_{\mathbf{x T O}}[\mathbf{M H z}]$ | $\mathbf{f}_{\mathbf{R F}}$ |
| :---: | :---: | :---: |
| 433.92 (ATA8202) | 13.57375 | $\mathrm{f}_{\mathrm{XTO}} \times 32-440 \mathrm{kHz}$ |
| 315.0 (ATA8201) | 13.1433 | $\mathrm{f}_{\mathrm{XTO}} \times 24-440 \mathrm{kHz}$ |

Attention must be paid to the harmonics of the CLK_OUT output signal $\mathrm{f}_{\text {CLK_OUT }}$ as well as to the harmonics produced by an microprocessor clocked with it, since these harmonics can disturb the reception of signals if they get to the RF input. If the CLK_OUT signal is used, it must be carefully laid out on the application PCB. The supply voltage of the microcontroller must also be carefully blocked.

### 3.1 Pin CLK_OUT

Pin CLK_OUT is an output to clock a connected microcontroller. The clock is available in Standby and Active modes. The frequency $\mathrm{f}_{\text {Clk_out }}$ can be adjusted via the pins CLK_OUT_CTRLO and CLK_OUT_CTRL1, and is calculated as follows:

Table 3-2. $\quad$ Setting of $\mathrm{f}_{\text {CLK_OUT }}$

| CLK_OUT_CTRL1 | CLK_OUT_CTRLO | Function |
| :---: | :---: | :---: |
| 0 | 0 | Clock on pin CLK_OUT is switched off <br> (Low level on pin CLK_OUT) |
| 0 | 1 | $\mathrm{f}_{\text {CLK_OUT }}=\mathrm{f}_{\text {XTO }} / 3$ |
| 1 | 0 | $\mathrm{f}_{\text {CLK_OUT }}=\mathrm{f}_{\text {XTO }} / 6$ |
| 1 | 1 | $\mathrm{f}_{\text {CLK_OUT }}=\mathrm{f}_{\text {XTO }} / 12$ |

The signal at CLK_OUT output has a nominal $50 \%$ duty cycle. To save current, it is recommended that CLK_OUT be switched off during Standby mode.

### 3.2 Basic Clock Cycle of the Digital Circuitry

The complete timing of the digital circuitry is derived from one clock. As seen in Figure 3-2 on page 17, this clock cycle, $\mathrm{T}_{\text {DCLK }}$, is derived from the crystal oscillator (XTO) in combination with a divider.
$f_{\text {DCLK }}=\frac{f_{\text {XTO }}}{16}$
$\mathrm{T}_{\text {DCLK }}$ controls the following application relevant parameters:

- Debouncing of the data signal stream
- Start-up time of the RX signal path

The start-up time and the debounce characteristic depend on the selected bit rate range (BR_Range) which is defined by pins BRO and BR1. The clock cycle $\mathrm{T}_{\text {XDCLK }}$ is defined by the following formulas for further reference:
BR_Range $\Rightarrow$
BR_Range 0: $\mathrm{T}_{\text {XDCLK }}=8 \times \mathrm{T}_{\text {DCLK }}$
BR_Range 1: $\mathrm{T}_{\text {XDCLK }}=4 \times \mathrm{T}_{\text {DCLK }}$
BR_Range 2: $\mathrm{T}_{\text {XDCLK }}=2 \times \mathrm{T}_{\text {DCLK }}$
BR_Range 3: $\mathrm{T}_{\text {XDCLK }}=1 \times \mathrm{T}_{\text {DCLK }}$

## ATA8201/ATA8202

## 4. Sensitivity Reduction

The output voltage of the RSSI amplifier is internally compared to a threshold voltage $\mathrm{V}_{\text {Th_red }}$. $\mathrm{V}_{\text {Th_red }}$ is determined by the value of the external resistor $\mathrm{R}_{\text {Sense }}$. $\mathrm{R}_{\text {Sense }}$ is connected between the pins SENSE and VS3V_AVCC (see Figure 10-1 on page 29). The output of the comparator is fed into the digital control logic. By this means, it is possible to operate the receiver at a lower sensitivity.

If the level on input pin SENSE_CTRL is low, the receiver operates at full sensitivity.
If the level on input pin SENSE_CTRL is high, the receiver operates at a lower sensitivity. The reduced sensitivity is defined by the value of $\mathrm{R}_{\text {Sense }}$, the maximum sensitivity by the sig-nal-to-noise ratio of the LNA input. The reduced sensitivity depends on the signal strength at the output of the RSSI amplifier.

Since different RF input networks may exhibit slightly different values for the LNA gain, the sensitivity values given in the electrical characteristics refer to a specific input matching. This matching is illustrated in Figure 2-1 on page 7 and exhibits the best possible sensitivity.

If the sensitivity reduction feature is not used, pin SENSE can be left open, pin SENSE_CTRL must be set to GND.

To operate with reduced sensitivity, pin SENSE_CTRL must be set to high before the RX signal path will be enabled by setting pin RX to high (see Figure 4-1 on page 20). As long as the RSSI level is lower than $\mathrm{V}_{\text {Th_red }}$ (defined by the external resistor $\mathrm{R}_{\text {Sense }}$ ) no data stream is available on pin DATA_OUT (low level on pin DATA_OUT). An internal RS flip-flop will be set to high the first time the RSSI voltage crosses $\mathrm{V}_{\text {Th_red }}$, and from then on the data stream will be available on pin DATA_OUT. From then on the receiver also works with full sensitivity. This makes sure that a telegram will not be interrupted if the RSSI level varies during the transmission. The RS flip-flop can be set back, and thus the receiver switched back to reduced sensitivity, by generating a positive pulse on pin ASK_NFSK (see Figure 4-2 on page 20). In FSK mode, operating with reduced sensitivity follows the same way.

Figure 4-1. Reduced Sensitivity Active


Figure 4-2. Restart Reduced Sensitivity


## 5. Power Supply

Figure 5-1. Power Supply


The supply voltage range of the ATA8201/ATA8202 is 2.7 V to 3.3 V or 4.5 V to 5.5 V .
Pin VS3V_AVCC is the supply voltage input for the range 2.7 V to 3.3 V , and is used in battery applications using a single lithium 3 V cell. Pin VS5V is the voltage input for the range 4.5 V to 5.5 V (car applications) in this case the voltage regulator V_REG regulates VS3V_AVCC to typically 3.0 V . If the voltage regulator is active, a blocking capacitor of $2.2 \mu \mathrm{~F}$ has to be connected to VS3V_AVCC (see Figure 10-1 on page 29).
DVCC is the internal operating voltage of the digital control logic and is fed via the switch SW_DVCC by VS3V_AVCC. DVCC must be blocked on pin DVCC with 68 nF (see Figure 9-1 on page 28 and Figure 10-1 on page 29).

Pin RX is the input to activate the RX signal processing and set the receiver to Active mode.

### 5.1 OFF Mode

A low level on pin RX and ENABLE will set the receiver to OFF mode (low power mode). In this mode, the crystal oscillator is shut down and no clock is available on pin CLK_OUT. The receiver is not sensitive to a transmitter signal in this mode.

Table 5-1. Standby Mode

| RX | ENABLE | Function |
| :---: | :---: | :---: |
| 0 | 0 | OFF mode |

### 5.2 Standby Mode

The receiver activates the Standby mode if pin ENABLE is set to "1".
In Standby mode, the XTO is running and the clock on pin CLK_OUT is available after the start-up time of the XTO has elapsed (dependent on pin CLK_OUT_CTRLO and CLK_OUT_CTRL1). During Standby mode, the receiver is not sensitive to a transmitter signal.

In Standby mode, the RX signal path is disabled and the power consumption $\mathrm{I}_{\text {Standby }}$ is typically $50 \mu \mathrm{~A}$ (CLK_OUT output off, VS3V_AVCC $=\mathrm{VS5V}=3 \mathrm{~V}$ ). The exact value of this current is strongly dependent on the application and the exact operation mode, therefore check the section "Electrical Characteristics: General" on page 30 for the appropriate application case.

Table 5-2. Standby Mode

| RX | ENABLE | Function |
| :---: | :---: | :---: |
| 0 | 1 | Standby mode |

Figure 5-2. Standby Mode (CLK_OUT_CTRL0 or CLK_OUT_CTRL1 = 1)


### 5.3 Active Mode

The Active mode is enabled by setting the level on pin RX to high. In Active mode, the RX signal path is enabled and if a valid signal is present it will be transferred to the connected microcontroller.

Table 5-3. Active Mode

| RX | ENABLE | Function |
| :---: | :---: | :---: |
| 1 | 1 | Active mode |

During $T_{\text {Startup_PLL }}$ the PLL is enabled and starts up. If the PLL is locked, the signal processing circuit starts up ( $T_{\text {Startup_Sig_Proc }}$ ). After the start-up time, all circuits are in stable condition and ready to receive. The duration of the start-up sequence depends on the selected bit rate range.

Figure 5-3. Active Mode


Table 5-4. Start-up Time

| BR1 | BR0 | ATA8202 (433.92 MHz) |  | ATA8201 (315 MHz) |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{T}_{\text {Startup_PLL }}$ | $\mathrm{T}_{\text {Startup_Sig_Proc }}$ | $\mathrm{T}_{\text {Startup_PLL }}$ | $\mathrm{T}_{\text {Startup_Sig_Proc }}$ |
| 0 | 0 | 261 us | 1096 s | 269 ¢s | 1132 s |
| 0 | 1 |  | 644 ¢s |  | 665 нs |
| 1 | 0 |  | 417 нs |  | 431 нs |
| 1 | 1 |  | 304 ¢ |  | 324 ¢ |

Table 5-5. Modulation Scheme

| ASK_NFSK | RF $_{\text {IN }}$ at Pin LNA_IN | Level at Pin DATA_OUT |
| :---: | :---: | :---: |
| 0 | $\mathrm{f}_{\text {FSK_H }}$ | 1 |
|  | $\mathrm{f}_{\text {FSK_L }}$ | 0 |
| 1 | $\mathrm{f}_{\mathrm{ASK}}$ on | 1 |
|  | $\mathrm{f}_{\mathrm{ASK}}$ off | 0 |

## 6. Bit Rate Ranges

Configuration of the bit rate ranges is carried out via the two pins BR0 and BR1. The microcontroller uses these two interface lines to set the corner frequencies of the band-pass data filter. Switching the bit rate ranges while the RF front end is in Active mode can be done on the fly and will not take longer than $100 \mu \mathrm{~s}$ if done while remaining in either ASK or FSK mode. If the modulation scheme is changed at the same time, the switching time is ( $\mathrm{T}_{\text {Startup_Sig_Proc }}$, see Figure 7-1 on page 26). Each BR_Range is defined by a minimum edge-to-edge time. To maintain full sensitivity of the receiver, edge-to-edge transition times of incoming data should not be less than the minimum for the selected BR_Range.

Table 6-1. $\quad$ BR Ranges ASK

| BR1 | BR0 | BR_Range | Recommended Bit Rate (Manchester) ${ }^{(1)}$ | Minimum Edge-to-edge Time Period $\mathrm{T}_{\mathrm{EE}}$ of the Data Signal ${ }^{(2)}$ | Edge-to-edge Time Period $\mathrm{T}_{\text {EE }}$ of the Data Signal During the Start-up Period ${ }^{(3)}$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | BR_Range0 | 1.0 Kbit/s to 2.5 Kbits/s | $200 \mu \mathrm{~s}$ | $200 \mu \mathrm{~s}$ to $500 \mu \mathrm{~s}$ |
| 0 | 1 | BR_Range1 | 2.0 Kbits/s to 5.0 Kbits/s | $100 \mu \mathrm{~s}$ | $100 \mu \mathrm{~s}$ to $250 \mu \mathrm{~s}$ |
| 1 | 0 | BR_Range2 | 4.0 Kbits/s to 10.0 Kbits/s | $50 \mu \mathrm{~s}$ | $50 \mu \mathrm{~s}$ to $125 \mu \mathrm{~s}$ |
| 1 | 1 | BR_Range3 | 8.0 Kbits/s to 10.0 Kbits/s | $50 \mu \mathrm{~s}$ | $50 \mu \mathrm{~s}$ to $62.5 \mu \mathrm{~s}$ |

Table 6-2. $\quad$ BR Ranges FSK

| BR1 | BR0 | BR_Range | Recommended Bit Rate <br> (Manchester) $^{(1)}$ | Minimum Edge-to-edge <br> Time Period TEE of the Data <br> Signal ${ }^{(2)}$ | Edge-to-edge Time Period $\mathbf{T}_{\mathrm{EE}}$ of <br> the Data Signal During the Start-up <br> Period |
| :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 0 | BR_Range0 | $1.0 \mathrm{Kbit} / \mathrm{s}$ to $2.5 \mathrm{Kbits} / \mathrm{s}$ | $200 \mu \mathrm{~s}$ | $200 \mu \mathrm{~s}$ to $500 \mu \mathrm{~s}$ |
| 0 | 1 | BR_Range1 | $2.0 \mathrm{Kbits} / \mathrm{s}$ to $5.0 \mathrm{Kbits} / \mathrm{s}$ | $100 \mu \mathrm{~s}$ | $100 \mu \mathrm{~s}$ to $250 \mu \mathrm{~s}$ |
| 1 | 0 | BR_Range2 | $4.0 \mathrm{Kbits} / \mathrm{s}$ to $10.0 \mathrm{Kbits} / \mathrm{s}$ | $50 \mu \mathrm{~s}$ | $50 \mu \mathrm{~s}$ to $125 \mu \mathrm{~s}$ |
| 1 | 1 | BR_Range3 | $8.0 \mathrm{Kbits} / \mathrm{s}$ to $20.0 \mathrm{Kbits} / \mathrm{s}$ | $25 \mu \mathrm{~s}$ | $25 \mu \mathrm{~s}$ to $62.5 \mu \mathrm{~s}$ |

Note: If during the start-up period ( $\mathrm{T}_{\text {Startup_PLL }}+\mathrm{T}_{\text {Startu__Sig_Proc }}$ ) there is no RF signal, the data filter settles to the noise floor, leading to noise on pin DATA_OUT.
Notes: 1. As can be seen, a bit stream of, for example, $2.5 \mathrm{Kbits} / \mathrm{s}$ can be received in BR_Range0 and BR_Range1 (overlapping BR_Ranges). To get the full sensitivity, always use the lowest possible BR_Range (here, BR_Range0). The advantage in the next higher BR_Range (BR_Range1) is the shorter start-up period, meaning lower current consumption during Polling mode. Thus, it is a decision between sensitivity and current consumption.
2. The receiver is also capable of receiving non-Manchester-modulated signals, such as PWM, PPM, VPWM, NRZ. In ASK mode, the header and blanking periods occurring in Keeloq-like protocols (up to 52 ms ) are supported.
3. To ensure an accurate settling of the data filter during the start-up period ( $\mathrm{T}_{\text {Startup_PLL }}+\mathrm{T}_{\text {Startup_Sig_Proc }}$ ), the edge-to-edge time $\mathrm{T}_{\text {EE }}$ of the data signal (preamble) must be inside the given limits during this period.

Figure 6-1. Examples of Supported Modulation Formats


Figure 6-2. Supported Header and Blanking Periods


## 7. ASK_NFSK

The ASK_NFSK pin allows the microcontroller to rapidly switch the RF front end between demodulation modes. A logic 1 on this pin selects ASK mode, and a logic 0 FSK mode. The time to change modes ( $T_{\text {Startup_Sig_Proc }}$ ) depends on the bit rate range being selected (not current bit rate range) and is given in Table 5-4 on page 23. This response time is specified for applications that require an ASK preamble followed by FSK data (for typical TPM applications). During $\mathrm{T}_{\text {Startup_Sig_Proc }}$, the level on pin DATA_OUT is low.

Figure 7-1. ASK Preamble 2.4 Kbits/s followed by FSK Data 9.6 Kbits/s


## 8. Polling Current Calculation

Figure 8-1. Polling Cycle


In an industrial or aftermarket RKE and TPM system, the average chip current in Polling mode, $\mathrm{I}_{\text {Polling }}$, is an important parameter. The polling period must be controlled by the connected microcontroller via the pins ENABLE and RX. The polling current can be calculated as follows:
$I_{\text {Polling }}=\left(T_{\text {Startup_PLL }} / T_{\text {Polling_Period }}\right) \times I_{\text {Startup_PLL }}+\left(T_{\text {Startup_Sig_Proc }} / T_{\text {Polling_Period }}\right) \times I_{\text {Active }}+$ $\left(T_{\text {Bitcheck }} / T_{\text {Polling_Period }}\right) \times I_{\text {Active }}+\left(T_{\text {Polling_Period }}-T_{\text {Startup_PLL }}-T_{\text {Startup_Sig_Proc }}-T_{\text {Bitcheck }}\right) /$ $\mathrm{T}_{\text {Polling_Period }} \times \mathrm{I}_{\text {Standby }}$
T Startup_PLL: depends on $315 \mathrm{MHz} / 433.92 \mathrm{MHz}$ application.
$\mathrm{T}_{\text {Startup_Sig_Proc: }}$ depends on $315 \mathrm{MHz} / 433.92 \mathrm{MHz}$ application and the selected bit rate range.
$\mathrm{T}_{\text {Bitcheck: }}$ depends on the signal bit rate (1/ Signal_Bit_Rate).
$\mathrm{T}_{\text {Polling_Period }}$ :
$I_{\text {Startup_PLL: }}$
$I_{\text {Active: }}$
$I_{\text {Standby }}:$
Example:- $\quad 315-\mathrm{MHz}$ application (ATA8201), bit rate: $9.6 \mathrm{Kbits} / \mathrm{s}, \mathrm{T}_{\text {Polling_Period }}=8 \mathrm{~ms}$
--> $\mathrm{T}_{\text {Startup_PLL }}=269 \mu \mathrm{~s}$
--> TStartup_Sig_Proc $=324 \mu \mathrm{~s} \quad$ (Bit Rate Range 3)
--> $\mathrm{T}_{\text {Bitcheck }} \quad=104 \mu \mathrm{~s}$
3V application; ASK mode, CLK_OUT disabled
--> I Itartup_PLL $=4.5 \mathrm{~mA}$
--> $I_{\text {Active }} \quad=\quad 6.5 \mathrm{~mA}$
$-->I_{\text {Standby }}=0.05 \mathrm{~mA}$
$-->I_{\text {Polling }}=0.545 \mathrm{~mA}$

## 9. 3V Application

Figure 9-1. 3 V Application


Note: Paddle (backplane) must be connected to GND

## 10. 5V Application

Figure 10-1. 5V Application With Reduced/Full Sensitivity


Note: Paddle (backplane) must be connected to GND

## 11. Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

| Parameters | Symbol | Min. | Max. | Unit |
| :--- | :---: | :---: | :---: | :---: |
| Junction temperature | $\mathrm{T}_{\mathrm{j}}$ |  | +150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {stg }}$ | -55 | +125 | ${ }^{\circ} \mathrm{C}$ |
| Ambient temperature | Tamb | -40 | ${ }^{\circ} \mathrm{C}$ |  |
| Supply voltage VS5V | $\mathrm{V}_{\mathrm{S}}$ |  | +6 | V |
| ESD (Human Body Model ESD S 5.1) <br> every pin | HBM | -4 | kV |  |
| ESD (Machine Model JEDEC A115A) <br> every pin | MM | -200 | +4 | V |
| ESD (Field Induced Charge Device Model ESD <br> STM 5.3.1-1999) every pin | FCDM | -500 | +500 | V |
| Maximum input level, input matched to $50 \Omega$ | $\mathrm{P}_{\text {in_max }}$ |  | dBm |  |

## 12. Thermal Resistance

| Parameters | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Junction ambient | $\mathrm{R}_{\mathrm{thJA}}$ | 25 | K/W |

## 13. Electrical Characteristics: General

All parameters refer to GND and are valid for $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS55}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 1 | OFF Mode |  |  |  |  |  |  |  |  |
| 1.1 | Supply current in OFF mode | $\begin{aligned} & \mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VS5V }} \leq 3 \mathrm{~V} \\ & \mathrm{~V}_{\text {VS5V }}=5 \mathrm{~V} \\ & \text { CLK_OUT disabled } \end{aligned}$ | $\begin{gathered} 10,11 \\ 10 \end{gathered}$ | $I_{\text {SOFF }}$ |  |  | $\begin{aligned} & 4 \\ & 4 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{A} \\ & \mu \mathrm{~A} \end{aligned}$ | $\begin{aligned} & \text { A } \\ & \text { A } \end{aligned}$ |
| 2 | Standby Mode |  |  |  |  |  |  |  |  |
| 2.1 | RF operating frequency range | ATA8201 | 14 | $\mathrm{f}_{\mathrm{RF}}$ | 313 |  | 317 | MHz | A |
|  |  | ATA8202 | 14 | $\mathrm{f}_{\mathrm{RF}}$ | 433 |  | 435 | MHz | A |
| 2.2 | Supply current Standby mode | XTO running <br> $\mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VS5V }} \leq 3 \mathrm{~V}$ <br> CLK_OUT disabled | 10,11 | $I_{\text {Standby }}$ |  | 50 | 100 | $\mu \mathrm{A}$ | A |
|  |  | XTO running <br> $\mathrm{V}_{\text {VS5V }}=5 \mathrm{~V}$ <br> CLK_OUT disabled | 10,11 | $I_{\text {Standby }}$ |  | 50 | 100 | $\mu \mathrm{A}$ | A |
| 2.3 | System start-up time | XTO startup XTAL: $\mathrm{C}_{\mathrm{m}}=5 \mathrm{fF}$, $\mathrm{C}_{0}=1.8 \mathrm{pF}, \mathrm{R}_{\mathrm{m}}=15 \Omega$ |  | $\mathrm{T}_{\text {XTO_Startup }}$ |  | 0.3 |  | ms | A |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\mathrm{IN}}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 2.4 | Active mode start-up time | From Standby mode to Active mode BR_Range_3 ATA5745 ATA5746 |  | $\mathrm{T}_{\text {Startup_PLL }}+$ <br> $T_{\text {Startup_Sig_Proc }}$ |  |  | $\begin{aligned} & 565 \\ & 593 \end{aligned}$ | $\begin{aligned} & \mu \mathrm{s} \\ & \mu \mathrm{~s} \end{aligned}$ | A |
| 3 | Active Mode |  |  |  |  |  |  |  |  |
| 3.1 | Supply current Active mode | $\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=3 \mathrm{~V}$ <br> ASK mode CLK_OUT disabled SENSE_CTRL $=0$ | 10,11 | $\mathrm{I}_{\text {Active }}$ |  | 6.5 |  | mA | A |
|  |  | $\mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VS5V }}=3 \mathrm{~V}$ FSK mode CLK_OUT disabled SENSE_CTRL = 0 | 10,11 | $I_{\text {Active }}$ |  | 6.7 |  | mA | A |
|  |  | $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$ <br> ASK mode CLK_OUT disabled SENSE_CTRL = 0 | 10 | $\mathrm{I}_{\text {Active }}$ |  | 6.7 |  | mA | A |
|  |  | $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$ <br> FSK mode CLK_OUT disabled SENSE_CTRL = 0 | 10 | $\mathrm{I}_{\text {Active }}$ |  | 6.9 |  | mA | A |
| 3.2 | Supply current Polling mode | $\mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VS5V }}=3 \mathrm{~V}$ <br> $\mathrm{T}_{\text {Polling_Period }}=8 \mathrm{~ms}$ <br> BR_Range_3, ASK mode, <br> CLK_OUT disabled <br> Data rate = 9.6 Kbits/s | 10,11 | $\mathrm{I}_{\text {Polling }}$ |  | 545 |  | $\mu \mathrm{A}$ | C |
| 3.3 | Input sensitivity FSK$\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | FSK deviation $\begin{aligned} & \mathrm{f}_{\mathrm{DEV}}= \pm 38 \mathrm{kHz} \\ & \mathrm{BER}=10^{-3} \\ & \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  |  |  |  |  |  |
|  |  | Bit rate 9.6 Kbits/s BR2 | (14) | $\mathrm{P}_{\text {REF_FSK }}$ | -103 | -105 | -106.5 | dBm | B |
|  |  | Bit rate 2.4 Kbits/s BR0 | (14) | $\mathrm{P}_{\text {REF_FSK }}$ | -106 | -108 | -109.5 | dBm | B |
|  |  | FSK deviation $\pm 18 \mathrm{kHz}$ to $\pm 50 \mathrm{kHz}$ |  |  |  |  |  |  |  |
|  |  | Bit rate 9.6 Kbits/s BR2 | (14) | $\mathrm{P}_{\text {REF_FSK }}$ | -101 |  |  | dBm | B |
|  |  | Bit rate 2.4 Kbits/s BR0 | (14) | $\mathrm{P}_{\text {REF_FSK }}$ | -104 |  |  | dBm | B |
| 3.4 | Input sensitivity ASK$\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | ASK 100\% level of carrier, $\begin{aligned} & \mathrm{BER}=10^{-3} \\ & \mathrm{~T}_{\mathrm{amb}}=25^{\circ} \mathrm{C} \end{aligned}$ |  |  |  |  |  |  |  |
|  |  | Bit rate 9.6 Kbits/s BR2 | (14) | $\mathrm{P}_{\text {REF_ASK }}$ | -109 | -111 | -112.5 | dBm | B |
|  |  | Bit rate 2.4 Kbits/s BR0 | (14) | $\mathrm{P}_{\text {REF_ASK }}$ | -112 | -114 | -115.5 | dBm | B |

*) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\text {IN }}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.5 | Sensitivity change at $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ compared to $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | $\begin{aligned} & \hline \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \text { to } \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \\ & \mathrm{P}=\mathrm{P}_{\mathrm{REF}} \mathrm{ASK}^{2}+\Delta \mathrm{P}_{\mathrm{REF} 1} \\ & \mathrm{P}=\mathrm{P}_{\text {REF_FSK }}+\Delta \mathrm{P}_{\text {REF }} \end{aligned}$ | (14) | $\Delta \mathrm{P}_{\text {REF } 1}$ |  | +1 |  | dB | B |
| 3.6 | Sensitivity change versus temperature, supply voltage and frequency offset |  | (14) | $\Delta \mathrm{P}_{\text {REF2 }}$ | +4.5 |  | -1.5 |  | B |
| 3.7 | Reduced sensitivity | $\mathrm{R}_{\text {Sense }}$ connected from pin SENSE to pin VS3V_AVCC |  | $\mathrm{P}_{\text {Ref_Red }}$ |  |  |  | dBm (peak level) |  |
|  |  | $\begin{aligned} & \mathrm{R}_{\text {Sense }}=62 \mathrm{k} \Omega \\ & \mathrm{f}_{\text {in }}=433.92 \mathrm{MHz} \end{aligned}$ |  |  |  | -76 |  | dBm | C |
|  |  | $\begin{aligned} & \mathrm{R}_{\text {Sense }}=82 \mathrm{k} \Omega \\ & \mathrm{f}_{\mathrm{in}}=433.92 \mathrm{MHz} \end{aligned}$ |  |  |  | -88 |  | dBm | C |
|  |  | $\begin{aligned} & \mathrm{R}_{\text {Sense }}=62 \mathrm{k} \Omega \\ & \mathrm{f}_{\mathrm{in}}=315 \mathrm{MHz} \end{aligned}$ |  |  |  | -76 |  | dBm | C |
|  |  | $\begin{aligned} & \mathrm{R}_{\text {Sense }}=82 \mathrm{k} \Omega \\ & \mathrm{f}_{\text {in }}=315 \mathrm{MHz} \end{aligned}$ |  |  |  | -88 |  | dBm | C |
|  | Reduced sensitivity variation over full operating range | $\begin{aligned} & \hline \mathrm{R}_{\text {Sense }}=62 \mathrm{k} \Omega \\ & \mathrm{R}_{\text {Sense }}=82 \mathrm{k} \Omega \\ & \mathrm{P}_{\text {Red }}=\mathrm{P}_{\text {Ref_Red }}+\mathrm{P}_{\Delta \text { Red }} \\ & \hline \end{aligned}$ |  | $\Delta \mathrm{P}_{\text {Red }}$ | -10 |  | +10 | dB |  |
| 3.8 | Maximum frequency offset in FSK mode | Maximum frequency difference of $f_{\text {RF }}$ between receiver and transmitter in FSK mode ( $\mathrm{f}_{\mathrm{RF}}$ is the center frequency of the FSK signal with $\mathrm{f}_{\mathrm{BIT}}=10 \mathrm{Kbits} / \mathrm{s}$ $\mathrm{f}_{\mathrm{DEV}}= \pm 38 \mathrm{kHz}$ | (14) | $\Delta \mathrm{f}_{\text {OFFSET }}$ | -160 |  | +160 | kHz | B |
| 3.9 | Supported FSK frequency deviation | With up to 2 dB loss of sensitivity. Note that the tolerable frequency offset is 12 kHz lower for $f_{D E V}= \pm 50 \mathrm{kHz}$ than for $\mathrm{f}_{\mathrm{DEV}}= \pm 38 \mathrm{kHz}$, hence, <br> $\Delta \mathrm{f}_{\text {OFFSET }} \leq \pm 148 \mathrm{kHz}$ | (14) | $f_{\text {DEV }}$ | $\pm 18$ | $\pm 38$ | $\pm 50$ | kHz | B |
| 3.10 | System noise figure | $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | (14) | NF |  | 6.0 | 9 | dB | B |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ | (14) | NF |  | 7.0 | 10 | dB | B |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\mathrm{IN}}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.11 | Intermediate frequency | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ |  | $\mathrm{f}_{\text {IF }}$ |  | 440 |  | kHz | A |
|  |  | $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ |  | $\mathrm{f}_{\text {IF }}$ |  | 440 |  | kHz | A |
| 3.12 | System bandwidth | 3 dB bandwidth This value is for information only! Note that for crystal and system frequency offset calculations, $\Delta f_{\text {OFFSET }}$ must be used. | (14) | SBW |  | 435 |  | kHz | A |
| 3.13 | System out-band 3rd-order input intercept point | $\begin{aligned} & \Delta \mathrm{f}_{\text {meas } 1}=1.8 \mathrm{MHz} \\ & \Delta \mathrm{f}_{\text {meas2 }}=3.6 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \end{aligned}$ | (14) | IIP3 |  | -24 |  | dBm | C |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ | (14) | IIP3 |  | -23 |  | dBm | C |
| 3.14 | System outband input 1-dB compression point | $\begin{aligned} & \Delta \mathrm{f}_{\text {meas } 1}=1 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \end{aligned}$ | (14) | 11 dBCP |  | -31 | -36 | dBm | C |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ | (14) | 11 dBCP |  | -30 | -35 | dBm | C |
| 3.15 | LNA input impedance | $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | 14 | $Z_{\text {in_LNA }}$ |  | (72.4-j298) |  | $\Omega$ | C |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ | 14 | $\mathrm{Z}_{\text {in_LNA }}$ |  | (55-j216) |  | $\Omega$ | C |
| 3.16 | Maximum peak RF input level, ASK and FSK | BER < 100․ , ASK: $100 \%$ | (14) | $\mathrm{P}_{\text {IN_max }}$ |  | +5 | -10 | dBm | C |
|  |  | FSK: $\mathrm{f}_{\text {DEV }}= \pm 38 \mathrm{kHz}$ | (14) | $\mathrm{P}_{\text {IN_max }}$ |  | +5 | -10 | dBm | C |
| 3.17 | LO spurs at LNA_IN | $\mathrm{f}<1 \mathrm{GHz}$ | (14) |  |  |  | -57 | dBm | C |
|  |  | $\mathrm{f}>1 \mathrm{GHz}$ | (14) |  |  |  | -47 | dBm | C |
|  |  | $\begin{aligned} & \mathrm{f}_{\mathrm{LO}}=315.44 \mathrm{MHz} \\ & 2 \times \mathrm{f}_{\mathrm{LO}} \\ & 4 \times \mathrm{f}_{\mathrm{LO}} \end{aligned}$ | (14) |  |  | $\begin{aligned} & -90 \\ & -94 \\ & -68 \end{aligned}$ |  | dBm | C |
|  |  | $\begin{aligned} & \mathrm{f}_{\mathrm{LO}}=434.36 \mathrm{MHz} \\ & 2 \times \mathrm{f}_{\mathrm{LO}} \\ & 4 \times \mathrm{f}_{\mathrm{LO}} \\ & \hline \end{aligned}$ | (14) |  |  | $\begin{aligned} & -92 \\ & -88 \\ & -58 \end{aligned}$ |  | dBm | C |
| 3.18 | Image rejection | With the complete image band $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ | (14) |  | 24 | 30 |  | dB | A |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ | (14) |  | 24 | 30 |  | dB | A |
| 3.19 | Useful signal to interferer ratio | Peak level of useful signal to peak level of interferer for $\mathrm{BER}<10^{-3}$ with any modulation scheme of interferer |  |  |  |  |  |  |  |
|  |  | FSK BR_Ranges 0, 1, 2 | (14) | $\mathrm{SNR}_{\text {FSKO-2 }}$ |  | 2 | 3 | dB | B |
|  |  | FSK BR_Range_3 | (14) | $\mathrm{SNR}_{\text {FSK3 }}$ |  | 4 | 6 | dB | B |
|  |  | ASK ( $\mathrm{P}_{\text {RF }}<\mathrm{P}_{\text {RFIN_High }}$ ) | (14) | SNR ${ }_{\text {ASK }}$ |  | 10 | 14 | dB | B |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\mathrm{IN}}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 3.20 | RSSI output | Dynamic range | (14),17 | $\mathrm{D}_{\text {RSSI }}$ |  | 65 |  | dB | A |
|  |  | Lower level of range $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \end{aligned}$ | (14),17 | $\mathrm{P}_{\text {RFIN_Low }}$ |  | -110 |  | dBm | A |
|  |  | Upper level of range $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \end{aligned}$ | (14), 17 | $\mathrm{P}_{\text {RFIn_High }}$ |  | -45 |  | dBm | A |
|  |  | Gain | (14), 17 |  |  | 15 |  | $\mathrm{mV} / \mathrm{dB}$ | A |
|  |  | Output voltage range | (14), 17 | $\mathrm{V}_{\text {RSSI }}$ | 350 |  | 1600 | mV | A |
| 3.21 | Output resistance RSSI pin |  | 17 | $\mathrm{R}_{\text {RSSI }}$ | 8 | 10 | 12.5 | $\mathrm{k} \Omega$ | C |
| 3.22 | Blocking | Sensitivity (BER $=10^{-3}$ ) is reduced by 3 dB if a continuous wave blocking signal at $\pm \Delta f$ is $\Delta P_{\text {Block }}$ higher than the useful signal level (Bit rate $=10 \mathrm{Kbits} / \mathrm{s}$, FSK, $\mathrm{f}_{\mathrm{DEV}} \pm 38 \mathrm{kHz}$, Manchester code, BR_Range2) |  |  |  |  |  |  |  |
|  |  | $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 1.5 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 2 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 3 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 10 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 20 \mathrm{MHz} \end{aligned}$ | (14) | $\Delta \mathrm{P}_{\text {Block }}$ |  | $\begin{aligned} & 57.5 \\ & 63.0 \\ & 67.5 \\ & 72.0 \\ & 74.0 \end{aligned}$ |  | dBC | C |
|  |  | $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 1.5 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 2 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 3 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 10 \mathrm{MHz} \\ & \Delta \mathrm{f} \pm 20 \mathrm{MHz} \end{aligned}$ | (14) | $\Delta \mathrm{P}_{\text {Block }}$ |  | $\begin{aligned} & 56.5 \\ & 62.0 \\ & 66.5 \\ & 71.0 \\ & 73.0 \end{aligned}$ |  | dBC | C |
| 3.23 | CDEM | Capacitor connected to pin 23 (CDEM) | 23 |  | -5\% | 15 | +5\% | nF | D |

*) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\mathrm{IN}}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 4 | XTO |  |  |  |  |  |  |  |  |
| 4.1 | Transconductance XTO at start | At startup; after startup the amplitude is regulated to $V_{\text {PPXTAL }}$ | 7,8 | $\mathrm{g}_{\mathrm{m}, \text { хто }}$ |  | 20 |  | mS | B |
| 4.2 | XTO start-up time | $\begin{aligned} & \mathrm{C}_{0} \leq 2.2 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{m}}<14 \mathrm{fF} \\ & \mathrm{R}_{\mathrm{m}} \leq 120 \Omega \end{aligned}$ | 7,8 | $\mathrm{T}_{\text {XTO_Startup }}$ |  | 300 |  | $\mu \mathrm{s}$ | A |
| 4.3 | Maximum $\mathrm{C}_{0}$ of XTAL |  | 7,8 | $\mathrm{C}_{0 \text { max }}$ |  |  | 3.8 | pF | D |
| 4.4 | Pulling of LO frequency $\mathrm{f}_{\mathrm{LO}}$ due to $\mathrm{XTO}, \mathrm{C}_{\mathrm{L} 1}$ and $\mathrm{C}_{\mathrm{L} 2}$ versus temperature and supply changes | $\begin{aligned} & 1.0 \mathrm{pF} \leq \mathrm{C}_{0} \leq 2.2 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{m}}=4.0 \mathrm{fF} \text { to } 7.0 \mathrm{fF} \\ & \mathrm{R}_{\mathrm{m}} \leq 120 \Omega \end{aligned}$ | 3 | $\Delta \mathrm{f}_{\text {XTO }}$ | -5 |  | +5 | ppm | C |
| 4.5 | Amplitude XTAL after startup | $\begin{aligned} & \mathrm{C}_{\mathrm{m}}=5 \mathrm{fF}, \mathrm{C}_{0}=1.8 \mathrm{pF} \\ & \mathrm{R}_{\mathrm{m}}=15 \Omega \end{aligned}$ |  |  |  |  |  |  |  |
|  |  | V(XTAL1, XTAL2) peak-to-peak value | 7,8 | $\mathrm{V}_{\text {PPXTAL }}$ |  | 700 |  | mVpp | C |
|  |  | V(XTAL1) peak-to-peak value | 7,8 | $V_{\text {PPXTAL }}$ |  | 350 |  | mVpp | C |
| 4.6 | Maximum series resistance $R_{m}$ of XTAL at startup | $\mathrm{C}_{0} \leq 2.2 \mathrm{pF}$, small signal start impedance, this value is important for crystal oscillator startup | 7,8 | $\mathrm{Z}_{\text {XTAL12_START }}$ | -1400 | -2000 |  | $\Omega$ | B |
| 4.7 | Maximum series resistance $R_{m}$ of XTAL after startup | $\begin{aligned} & \mathrm{C}_{0} \leq 2.2 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{m}}<14 \mathrm{fF} \end{aligned}$ | 7,8 | $\mathrm{R}_{\mathrm{m} \text { _max }}$ |  | 15 | 120 | $\Omega$ | B |
| 4.8 | Nominal XTAL load resonant frequency | $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \end{aligned}$ | 7,8 | $\mathrm{f}_{\text {XTAL }}$ |  | $\begin{gathered} 13.57375 \\ 13.1433 \end{gathered}$ |  | MHz | D |
| 4.9 | External CLK_OUT frequency | $\begin{aligned} & \text { CLK_OUT_CRTL1 }=0 \\ & \text { CLK_OUT_CTRLO }=0 \\ & -->\text { CLK_OUT disabled } \end{aligned}$ | 3 | $\mathrm{f}_{\text {CLK_OUT }}$ | $\mathrm{f}_{\text {CLK }}$ disabled (low level on pin CLK_OUT) |  |  | MHz | A |
|  |  | $\begin{aligned} & \text { CLK_OUT_CRTL1=0 } \\ & \text { CLK_OUT_CTRL0 = }=1 \\ & -->\text { division ratio = } 3 \end{aligned}$ |  |  | $f_{\mathrm{CLK}}=\frac{\mathrm{f}_{\mathrm{XTO}}}{3}$ |  |  |  |  |
|  |  | $\begin{aligned} & \text { CLK_OUT_CRTL1 = } 1 \\ & \text { CLK_OUT_CTRL0 }=0 \\ & -->\text { division ratio }=6 \end{aligned}$ |  |  | $f_{\mathrm{CLK}}=\frac{\mathrm{f}_{\mathrm{XTO}}}{6}$ |  |  |  |  |
|  |  | $\begin{aligned} & \hline \text { CLK_OUT_CRTL1=1 }=1 \\ & \text { CLK_OUT_CTRL0 = } 1 \\ & -->\text { division ratio = } 12 \end{aligned}$ |  |  | $f_{\mathrm{CLK}}=\frac{\mathrm{f}_{\mathrm{XTO}}}{12}$ |  |  |  |  |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\mathrm{IN}}\right)$.

## 13. Electrical Characteristics: General (Continued)

All parameters refer to $G N D$ and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin ${ }^{(1)}$ | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ <br> CLK_OUT division ratio $\begin{aligned} & =3 \\ & =6 \end{aligned}$ $=12$ <br> CLK_OUT has nominal $50 \%$ duty cycle | 3 | $\mathrm{f}_{\text {CLK_OUT }}$ |  | $\begin{aligned} & 4.52458 \\ & 2.26229 \\ & 1.13114 \end{aligned}$ |  | MHz | D |
|  |  | $\mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz}$ <br> CLK_OUT division ratio $\begin{aligned} & =3 \\ & =6 \\ & =12 \end{aligned}$ <br> CLK_OUT has nominal 50\% duty cycle | 3 | $\mathrm{f}_{\text {CLK_OUT }}$ |  | $\begin{gathered} 4.3811 \\ 2.190 \\ 1.0952 \end{gathered}$ |  | MHz | D |
| 4.10 | DC voltage after startup | V ${ }_{\text {DC }}$ (XTAL1, XTAL2) XTO running (Standby mode, Active mode) | 7,8 | $V_{\text {DCXTO }}$ | -250 | -45 |  | mV | C |
| 5 | Synthesizer |  |  |  |  |  |  |  |  |
| 5.1 | Spurs in Active mode | At $\pm \mathrm{f}_{\text {CLK_OUT }}$, CLK_OUT enabled (division ratio $=3$ ) $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \end{aligned}$ |  | $\mathrm{SP}_{\mathrm{RX}}$ |  | -75 | -70 | dBC | C |
|  |  | $\begin{aligned} & \text { at } \pm \mathrm{f}_{\mathrm{XTO}} \\ & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \end{aligned}$ |  | $\mathrm{SP}_{\mathrm{RX}}$ |  | -75 | -70 | dBC | A |
| 5.2 | Phase noise at 3 MHz Active mode | $\begin{aligned} & \mathrm{f}_{\mathrm{RF}}=315 \mathrm{MHz} \\ & \mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz} \end{aligned}$ |  | $L_{\text {RX3M }}$ |  | -130 | -127 | $\mathrm{dBC} / \mathrm{Hz}$ | A |
| 5.3 | Phase noise at 20 MHz Active mode | Noise floor |  | $L_{\text {RX20M }}$ |  | -135 | -132 | $\mathrm{dBC} / \mathrm{Hz}$ | B |
| 6 | Microcontroller Interface |  |  |  |  |  |  |  |  |
| 6.1 | CLK_OUT output rise and fall time | $\begin{aligned} & \mathrm{f}_{\mathrm{CLK}} \text { ouT }<4.5 \mathrm{MHz} \\ & \mathrm{C}_{\mathrm{L}}=10 \mathrm{pF} \\ & \mathrm{C}_{\mathrm{L}}=\text { Load capacitance on } \\ & \text { pin CLK_OUT } \\ & 2.7 \mathrm{~V} \leq \mathrm{V}_{\text {VS5V }} \leq 3.3 \mathrm{~V} \text { or } \\ & 4.5 \mathrm{~V} \leq \mathrm{V}_{\text {VS5V }} \leq 5.5 \mathrm{~V} \\ & 20 \% \text { to } 80 \% \mathrm{~V}_{\text {VS5V }} \end{aligned}$ | 3 | $\begin{aligned} & t_{\text {rise }} \\ & t_{\text {fall }} \end{aligned}$ |  | $\begin{aligned} & 20 \\ & 20 \end{aligned}$ | $\begin{aligned} & 30 \\ & 30 \end{aligned}$ | ns ns | B |
| 6.2 | Internal equivalent capacitance | Used for current calculation | 3 | $\mathrm{C}_{\text {CLK_OUT }}$ |  | 8 |  | pF | B |

*) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
Note: 1. Pin numbers in parenthesis were measured with RF_IN matched to $50 \Omega$ according to Figure 2-1 on page 7 with component values as in Table 2-2 on page $7\left(\mathrm{RF}_{\text {IN }}\right)$.

## 14. Electrical Characteristic: 3V Application

All parameters refer to GND and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 7 | 3V Application |  |  |  |  |  |  |  |  |
| 7.1 | Supply current in OFF mode | $\mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VS5V }} \leq 3 \mathrm{~V}$ CLK_OUT disabled | 10, 11 | $\mathrm{I}_{\text {SOFF }}$ |  |  | 2 | $\mu \mathrm{A}$ | A |
| 7.2 | Supported voltage range | 3V application | 10, 11 | $\mathrm{V}_{\text {VS3V_AVCC }}$, $\mathrm{V}_{\text {VS5V }}$ | 2.7 |  | 3.3 | V | A |
| 7.3 | Current in Standby mode (XTO is running) | $\mathrm{V}_{\text {VS3V_AVCC }}=$ <br> $\mathrm{V}_{\text {VS5v }} \leq 3 \mathrm{~V}$ <br> external load C on pin <br> CLK_OUT = 12 pF <br> CLK enabled <br> (division ratio 3) <br> CLK enabled <br> (division ratio 6) <br> CLK enabled <br> (division ratio 12) <br> CLK disabled | 10, 11 | $I_{\text {Standby }}$ |  | 420 <br> 290 <br> 220 <br> 50 |  | $\mu \mathrm{A}$ | C <br> C <br> C <br> A |
| 7.4 | Current during $\mathrm{T}_{\text {Startup_PLL }}$ | $\mathrm{V}_{\text {VS3V_AVCC }}=$ <br> $\mathrm{V}_{\text {vs5v }} \leq 3 \mathrm{~V}$ <br> CLK disabled | 10, 11 | $\mathrm{I}_{\text {Startup_PLL }}$ |  | 4.5 |  | mA | C |
| 7.5 | Current in Active mode ASK | $\mathrm{V}_{\text {VS3V_AVCC }}=$ <br> $\mathrm{V}_{\text {vs5v }} \leq 3 \mathrm{~V}$ <br> CLK disabled <br> SENSE_CTRL $=0$ | 10, 11 | $\mathrm{I}_{\text {Active }}$ |  | 6.5 |  | mA | A |
| 7.6 | Current in Active mode FSK | $\mathrm{V}_{\text {VS3V_AVCC }}=$ <br> $\mathrm{V}_{\text {vs5v }} \leq 3 \mathrm{~V}$ <br> CLK disabled <br> SENSE_CTRL $=0$ | 10, 11 | $\mathrm{I}_{\text {Active }}$ |  | 6.7 |  | mA | A |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
15. Electrical Characteristics: 5V Application

All parameters refer to $G N D$ and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$ and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $f_{\mathrm{RF}}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics".

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 8 | 5V Application |  |  |  |  |  |  |  |  |
| 8.1 | Supply current in OFF mode | $V_{V S 5 V}=5 \mathrm{~V}$ <br> CLK_OUT disabled | 10 | $\mathrm{I}_{\text {SOFF }}$ |  |  | 2 | $\mu \mathrm{A}$ | A |
| 8.2 | Supported voltage range | 5 V application | 10 | $\mathrm{V}_{\text {VS5V }}$ | 4.5 |  | 5.5 | V | A |
| 8.3 | Current in Standby mode (XTO is running) | $\mathrm{V}_{\text {VS5v }} \leq 5 \mathrm{~V}$ external load C on pin CLK_OUT = 12 pF CLK enabled (division ratio 3) CLK enabled (division ratio 6) CLK enabled (division ratio 12) CLK disabled | 10 | $I_{\text {Standby }}$ |  | $\begin{aligned} & 700 \\ & 490 \\ & 370 \\ & 50 \\ & \hline \end{aligned}$ |  | $\mu \mathrm{A}$ | $\begin{aligned} & \mathrm{C} \\ & \mathrm{C} \\ & \mathrm{C} \\ & \mathrm{~A} \end{aligned}$ |
| 8.4 | Current during $\mathrm{T}_{\text {Startup_PLL }}$ | $V_{V S 5 \mathrm{~V}}=5 \mathrm{~V}$ <br> CLK disabled | 10 | $\mathrm{I}_{\text {Startup_PLL }}$ |  | 4.7 |  | mA | C |
| 8.5 | Current in Active mode ASK | $V_{V S 5 \mathrm{~V}}=5 \mathrm{~V}$ <br> CLK disabled <br> SENSE_CTRL = 0 | 10 | $\mathrm{I}_{\text {Active }}$ |  | 6.7 |  | mA | A |
| 8.6 | Current in Active mode FSK | $V_{\text {VS5V }}=5 \mathrm{~V}$ CLK disabled SENSE_CTRL = 0 | 10 | $\mathrm{I}_{\text {Active }}$ |  | 6.9 |  | mA | A |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter

## 16. Digital Timing Characteristics

All parameters refer to GND and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics"

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 9 | Basic Clock Cycle of the Digital Circuitry |  |  |  |  |  |  |  |  |
| 9.1 | Basic clock cycle |  |  | $\mathrm{T}_{\text {DCLK }}$ | 16 / fxto |  | 16 / f ${ }_{\text {xTO }}$ | $\mu \mathrm{s}$ | A |
| 9.2 | Extended basic clock cycle | BR_Range_0 BR_Range_1 BR_Range_2 BR_Range_3 |  | $\mathrm{T}_{\text {XDCLK }}$ | $\begin{array}{r} \hline 8 \\ 4 \\ 2 \\ 1 \\ \times \mathrm{T}_{\mathrm{DCLK}} \end{array}$ |  | $\begin{array}{r} 8 \\ 4 \\ 2 \\ 1 \\ \times \mathrm{T}_{\mathrm{DCLK}} \end{array}$ | $\mu \mathrm{s}$ | A |
| 10 | Active Mode |  |  |  |  |  |  |  |  |
| 10.1 | Startup PLL |  |  | $\mathrm{T}_{\text {Startup_PLL }}$ |  |  | $15 \mu \mathrm{~s}+$ $208 \times$ <br> TDCLK | $\mu \mathrm{s}$ | A |
| 10.2 | Startup signal processing | BR_Range_0 BR_Range_1 BR_Range_2 BR_Range_3 |  | $\mathrm{T}_{\text {Startup_Sig_Proc }}$ | $\begin{array}{r} 929.5 \\ 545.5 \\ 353.5 \\ 257.5 \\ \times \mathrm{T}_{\text {DCLK }} \end{array}$ |  | $\begin{gathered} 929.5 \\ 545.5 \\ 353.5 \\ 257.5 \\ \times \mathrm{T}_{\text {DCLK }} \end{gathered}$ |  | A |
| 10.3 | Bit rate range | ASK <br> BR_Range = <br> BR_Range0 <br> BR_Range1 <br> BR_Range2 <br> BR_Range3 FSK <br> BR_Range = <br> BR_Range0 <br> BR_Range1 <br> BR_Range2 <br> BR_Range3 |  | BR_Range | $\begin{aligned} & 1.0 \\ & 2.0 \\ & 4.0 \\ & 8.0 \\ & \\ & 1.0 \\ & 2.0 \\ & 4.0 \\ & 8.0 \end{aligned}$ |  | $\begin{gathered} 2.5 \\ 5.0 \\ 10.0 \\ 10.0 \\ \\ 2.5 \\ 5.0 \\ 10.0 \\ 20.0 \end{gathered}$ | Kbits/s | A |
| 10.4 | Minimum time period between edges at pin DATA_OUT | BR_Range_0 <br> BR_Range_1 <br> BR_Range_2 <br> BR_Range_3 | 24 | $\mathrm{T}_{\text {DATA_OUT_min }}$ | $\begin{gathered} 10 \times \\ \mathrm{T}_{\text {XDCLK }} \end{gathered}$ |  |  | $\mu \mathrm{s}$ | A |
| 10.5 | Edge-to-edge time period of the data signal for full sensitivity in Active mode | BR_Range_0 BR_Range_1 BR_Range_2 BR_Range_3 |  | T DATA_OUT | $\begin{gathered} 200 \\ 100 \\ 50 \\ 25 \end{gathered}$ |  | $\begin{gathered} 500 \\ 250 \\ 125 \\ 62.5 \end{gathered}$ | $\mu \mathrm{s}$ | B |

[^0]
## 17. Digital Port Characteristics

All parameters refer to $G N D$ and are valid for $T_{\text {amb }}=25^{\circ} \mathrm{C}, \mathrm{V}_{\text {VS3V_AVCC }}=\mathrm{V}_{\text {VSSV }}=3 \mathrm{~V}$, and $\mathrm{V}_{\text {VSSV }}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics"

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 11 | Digital Ports |  |  |  |  |  |  |  |  |
| 11.1 | ENABLE input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V} \text { AVCC }}= \\ & \mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 6 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{~V} \text { AVCC }}= \\ & \mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}=4.5 \mathrm{~V} \text { to } \\ & 5.5 \mathrm{~V} \end{aligned}$ | 6 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  |  | V | A |
| 11.2 | RX input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V} \text { AVCC }}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 19 | $\mathrm{V}_{\text {II }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{VAVCC}}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 19 | $\mathrm{V}_{\text {Ih }}$ |  |  |  | V | A |
| 11.3 | BR0 input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{~V}} \mathrm{AVCC}= \\ & \mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 20 | $\mathrm{V}_{\text {II }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \text { V } \mathrm{AVCC}}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 20 | $\mathrm{V}_{\text {Ih }}$ |  |  |  | V | A |
| 11.4 | BR1 input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{VAVCC}}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 21 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V} \text { AVCC }}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 21 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  |  | V | A |
| 11.5 | ASK_NFSK input - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V} \text { AVCC }}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 22 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{~V}} \mathrm{AVCC}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 22 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\text {S }}$ |  |  | V | A |

${ }^{*}$ ) Type means: $\mathrm{A}=100 \%$ tested, $\mathrm{B}=100 \%$ correlation tested, $\mathrm{C}=$ Characterized on samples, $\mathrm{D}=$ Design parameter

## 17. Digital Port Characteristics (Continued)

All parameters refer to GND and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $\mathrm{f}_{\mathrm{RF}}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics"

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 11.6 | SENSE_CTRL input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{VACCC}}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 16 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{~V}} \mathrm{AVCC}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 16 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  |  | V | A |
| 11.7 | CLK_OUT_CTRLO input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 3 \mathrm{~V}-\mathrm{AVCC}}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 5 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{~V}} \mathrm{AVCC}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 5 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  |  | V | A |
| 11.8 | CLK_OUT_CTRL1 input <br> - Low level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V}} \mathrm{AVCC} \\ & \mathrm{~V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 4 | $\mathrm{V}_{\text {II }}$ |  |  | $\begin{gathered} 0.2 \times \mathrm{V}_{\mathrm{S}} \\ 0.12 \times \\ \mathrm{V}_{\mathrm{S}} \end{gathered}$ | V | A |
|  | - High level input voltage | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} \mathrm{AVCC}}= \\ & \mathrm{V}_{\mathrm{VS55}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \end{aligned}$ | 4 | $\mathrm{V}_{\text {Ih }}$ | $0.8 \times \mathrm{V}_{\mathrm{S}}$ |  |  | V | A |
| 11.9 | TEST1 input | TEST1 input must always be connected directly to GND | 2 |  | 0 |  | 0 | V | D |
| 11.10 | TEST2 output | TEST2 output must always be connected directly to GND | 1 |  | 0 |  | 0 | V | D |
| 11.11 | TEST3 input | TEST3 input must always be connected directly to GND | 18 |  | 0 |  | 0 | V | D |

[^1]
## 17. Digital Port Characteristics (Continued)

All parameters refer to GND and are valid for $T_{\mathrm{amb}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{VS3V} \text { _AVCC }}=\mathrm{V}_{\mathrm{VS5V}}=3 \mathrm{~V}$, and $\mathrm{V}_{\mathrm{VS5V}}=5 \mathrm{~V}$. Typical values are given at $f_{R F}=433.92 \mathrm{MHz}$ unless otherwise specified. Details about current consumption, timing, and digital pin properties can be found in the specific sections of the "Electrical Characteristics"

| No. | Parameters | Test Conditions | Pin | Symbol | Min. | Typ. | Max. | Unit | Type* |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 11.12 | DATA_OUT output - Saturation voltage low | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\text {VS3V }} \mathrm{AVCC}= \\ & \mathrm{V}_{\text {VS5V }}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{I}_{\text {DATA_OUT }}=250 \mu \mathrm{~A} \end{aligned}$ | 24 | $\mathrm{V}_{\text {ol }}$ |  | 0.15 | 0.4 | V | B |
|  | - Saturation voltage high | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS3V} 3 \mathrm{AVCC}}= \\ & \mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{I}_{\text {DATA_OUT }}=-250 \mu \mathrm{~A} \end{aligned}$ | 24 | $V_{\text {oh }}$ | $\mathrm{V}_{\mathrm{vs}}-0.4$ | $\begin{gathered} \mathrm{V}_{\mathrm{vs}}- \\ 0.15 \end{gathered}$ |  | V | B |
| 11.13 | CLK_OUT output <br> - Saturation voltage low | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\text {VS3VAVCC }}= \\ & \mathrm{V}_{\mathrm{VS} 5 \mathrm{~V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{I}_{\text {DATA_OUT }}=100 \mu \mathrm{~A} \end{aligned}$ | 3 | $\mathrm{V}_{\text {ol }}$ |  | 0.15 | 0.4 | V | B |
|  | - Saturation voltage high | $\begin{aligned} & \mathrm{V}_{\mathrm{S}}=\mathrm{V}_{\text {VS3VAVCC }}= \\ & \mathrm{V}_{\mathrm{VS5V}}=2.7 \mathrm{~V} \text { to } 3.3 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{S}}=\mathrm{V}_{\mathrm{VS5V}}= \\ & 4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V} \\ & \mathrm{I}_{\text {DATA_OUT }}=-100 \mu \mathrm{~A} \end{aligned}$ | 3 | $\mathrm{V}_{\text {oh }}$ | $\mathrm{V}_{\mathrm{vs}}-0.4$ | $\begin{gathered} \mathrm{V}_{\mathrm{vs}}- \\ 0.15 \end{gathered}$ |  | V | B |

${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter
18. Ordering Information

| Extended Type Number | Package | MOQ | Remarks |
| :--- | :---: | :---: | :--- |
| ATA8202-PXQW | QFN24 | 6000 pcs | $5 \mathrm{~mm} \times 5 \mathrm{~mm}, \mathrm{~Pb}-$ free, 433.92 MHz |
| ATA8201-PXQW | QFN24 | 6000 pcs | $5 \mathrm{~mm} \times 5 \mathrm{~mm}, \mathrm{~Pb}-$ free, 315 MHz |

19. Package Information

Package: QFN 24-5 x 5
Exposed pad $3.6 \times 3.6$
(acc. JEDEC OUTLINE No. MO-220)
Dimensions in mm
Not indicated tolerances $\pm 0.05$


Drawing-No.: 6.543-5122.01-4
Issue: 1; 15.11 .05


technical drawings according to DIN specifications

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[^0]:    ${ }^{*}$ ) Type means: $A=100 \%$ tested, $B=100 \%$ correlation tested, $C=$ Characterized on samples, $D=$ Design parameter

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